





LMC555

SNAS558N - JANUARY 2000 - REVISED MARCH 2024

LMC555 CMOS Timer

1 Features

Texas

INSTRUMENTS

- Fast astable frequency of 3MHz
- Available in industry's smallest 8-bump DSBGA package (1.43mm × 1.41mm)
- Less than 1mW typical power dissipation at 5V ٠ vlague
- 1.5V specified supply operating voltage
- output fully compatible with TTL and CMOS logic • at 5V supply
- Tested to -10mA, 50mA output current levels
- Reduced supply current spikes during output transitions
- Extremely low reset, trigger, and threshold currents
- Excellent temperature stability
- Pin-for-pin compatible with 555 series of timers

2 Applications

- Precision timing •
- Pulse generation
- Sequential timing
- Time delay generation
- Pulse width modulation
- Pulse position modulation
- Linear ramp generators

3 Description

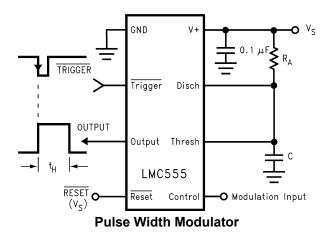
The LMC555 device is a CMOS version of the industry standard 555 series general-purpose timers. In addition to the standard SOIC, VSSSOP, and PDIP packages, the LMC555 is also available in a chipsized, 8-bump DSBGA package using TI's DSBGA package technology. The LMC555 offers the same capability of generating accurate time delays and frequencies as the LM555, but with much lower power dissipation and supply current spikes. When operated as a one-shot, the time delay is precisely controlled by a single external resistor and capacitor. In astable mode, the oscillation frequency and duty cycle are accurately set by two external resistors and one capacitor. TI's LMCMOS process extends both the frequency range and the low supply capability.

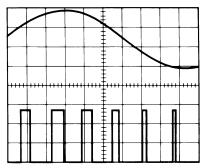
Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾			
	D (SOIC, 8)	4.9mm × 6mm			
LMC555	DGK (VSSOP, 8)	3mm × 4.9mm			
LIVIC555	P (PDIP, 8)	9.81mm × 9.43mm			
	YBF (DSBGA, 8)	1.75mm × 1.75mm			

(1) For more information, see Section 11.

(2) The package size (length × width) is a nominal value and includes pins, where applicable.





Pulse Width Modulator Waveform: Top Waveform—Modulation Bottom Waveform—Output Voltage





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4 Pin Configuration and Functions

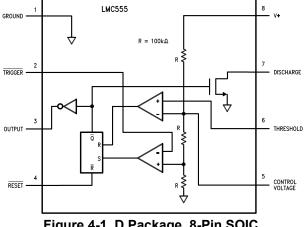
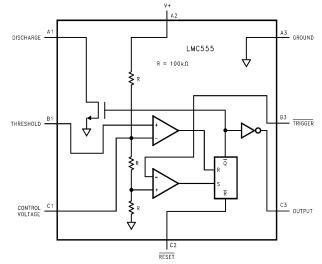
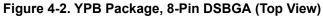


Figure 4-1. D Package, 8-Pin SOIC, DGK Package, 8-Pin VSSOP, and P Package, 8-Pin PDIP (Top View)





	PIN					
	NO.					
NAME	D (SOIC), DGK (VSSOP), P (PDIP)	YPB (DSBGA)	TYPE	DESCRIPTION		
CONTROL VOLTAGE	5	C1	Input	Control voltage controls the threshold and trigger levels. This pin determines the pulse duration of the output waveform. An external voltage applied to this pin can also be used to modulate the output waveform.		
DISCHARGE	7	A1	Input	Open collector output that discharges a capacitor between intervals (in phase with output). This pin toggles the output from high to low when voltage reaches 2/3 of the supply voltage (V+).		
GROUND	1	A3	Power	Ground reference voltage		
OUTPUT	3	C3	Output	Output driven waveform		
RESET	4	C2	Input	Negative pulse applied to this pin to disable or reset the timer. When not used for reset purposes, connect this pin to V+ to avoid false triggering.		
THRESHOLD	6	B1	Input	Compares the voltage applied to the pin with a reference voltage of 2/3 V+. The amplitude of voltage applied to this pin is responsible for the set state of the flip-flop.		
TRIGGER	2	В3	Input	Responsible for transition of the flip-flop from set to reset. The output of the timer depends on the amplitude of the external trigger pulse applied to this pin.		
V+	8	A2	Power	Supply voltage with respect to ground		

Table 4-1. Pin Functions

5 Specifications

5.1 Absolute Maximum Ratings

		MIN	MAX	UNIT
	Supply		15	
Voltage	Input	-0.3	(V+) + 0.3	V
	Output		15	
Current	Output		100	mA
Storage temperature,	T _{stg}	-65	150	°C

over operating free-air temperature range, unless otherwise noted.^{(1) (2) (3)}

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Section 5.3. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) See AN-1112 (SNVA009) for DSBGA considerations.

(3) If military- or aerospace-specified devices are required, contact the TI Sales Office or Distributors for availability and specifications.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
To many a market ma	LMC555IM	-40	125	°C
Temperature	LMC555CM, MM, N, TP	-40	85	C
Maximum allowable power dissipation at 25°C	PDIP-8		1126	
	SOIC-8		740	mW
	VSSOP-8		555	TIIVV
	8-bump DSBGA		568	

5.4 Thermal Information

			LMC555				
THERMAL METRIC ⁽¹⁾		D (SOIC)	DGK (VSSOP)	P (PDIP)	YPB (DSBGA)	UNIT	
		8 PINS	8 PINS	8 PINS	8 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	138.9	188.3	93.1	102.3	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	78.8	78.8	82.5	0.9	°C/W	
R _{θJB}	Junction-to-board thermal resistance	87.9	110.2	69.6	31.2	°C/W	
Ψ _{JT}	Junction-to-top characterization parameter	23.2	18.5	52.0	0.5	°C/W	
Ψ _{JB}	Junction-to-board characterization parameter	86.9	108.6	69.2	31.2	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W	

(1) For information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Electrical Characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		V _S = 1.5 V		130	200	
s	Supply current	V _S = 5 V		180	250	μA
		V _S = 12 V		220	400	
		V _S = 1.5 V	0.8	1.0	1.2	
/ _{CTRL}	Control voltage	V _S = 5 V	2.9	3.3	3.8	V
		V _S = 12 V	7.4	8.0	8.6	
,	Discharge esturation voltage	V _S = 1.5 V, I _{DIS} = 1 mA		75	150	mV
/ _{DIS}	Discharge saturation voltage	V _S = 5 V, I _{DIS} = 10 mA		150	300	mv
	Output voltage (low)	V _S = 1.5 V, I _O = 1 mA		0.2	0.4	V
/ _{OL}		V _S = 5 V, I _O = 8 mA		0.3	0.6	
		V _S = 12 V, I _O = 50 mA		1.0	2.0	
	Output voltage (high)	V _S = 1.5 V, I _O = -0.25 mA	1.0	1.25		V
/ _{он}		$V_{\rm S} = 5 \text{ V}, \text{ I}_{\rm O} = -2 \text{ mA}$	4.4	4.7		
		V _S = 12 V, I _O = −10 mA	10.5	11.3		
,	Trigger veltage	V _S = 1.5 V	0.4	0.5	0.6	
/ _{TRIG}	Trigger voltage	V _S = 12 V	3.7	4.0	4.3	V
TRIG	Trigger current	V _S = 5 V		10		pА
,	Depart voltage	$V_{\rm S} = 1.5 V^{(2)}$	0.4	0.7	1.0	V
/ _{RES}	Reset voltage	V _S = 12 V	0.4	0.75	1.1	v
	Depart ourrent	$V_{\rm S}$ = 5 V, $V_{\rm RES}$ = $V_{\rm S}$		10		pА
RES	S Reset current	V _S = 5 V, V _{RES} = 0 V		5.9		μA
THRESH	Threshold current	V _S = 5 V		10		pА
DIS	Discharge leakage	V _S = 12 V		1.0	100	nA

Test Circuit, T = 25°C, all switches open, $\overline{\text{RESET}}$ to V_S unless otherwise noted⁽¹⁾

(1) All voltages are measured with respect to the ground pin, unless otherwise specified.

(2) If the $\overline{\text{RESET}}$ pin is to be used at temperatures of -20°C and less, then ensure that V_S is 2.0 V or greater.

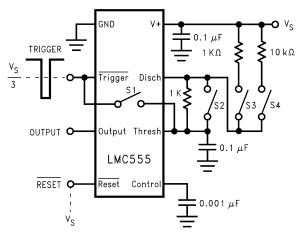
5.6 Switching Characteristics

Test Circuit, T = 25°C, all switches open, $\overline{\text{RESET}}$ to V_S unless otherwise noted.⁽¹⁾ Characteristic values are specified by design, characterization, or both.

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
			V _S = 1.5 V	0.9	1.1	1.25	
t	Timing accuracy	SW 2, 4 closed	V _S = 5 V	1.0	1.1	1.20	ms
			V _S = 12 V	1.0	1.1	1.25	
$\Delta t / \Delta V_S$	Timing shift with supply	V _S = 5 V ± 1 V	V _S = 5 V ± 1 V		0.3		%/V
Δt/ΔT	Timing shift with temperature	V _S = 5 V	V _S = 5 V		75		ppm/°C
f _A	Astable frequency	SW 1, 3 closed, V _S = 12 V		4.0	4.8	5.6	kHz
f _{MAX}	Maximum frequency	Maximum frequency test circuit, V _S = 5 V			3.0		MHz
t _R , t _F	Output rise and fall times	Maximum frequency test circuit $V_S = 5 V, C_L = 10 pF$			15		ns
t _{PD}	Trigger propagation delay	V _S = 5 V, measure from trigger to outp			100		ns

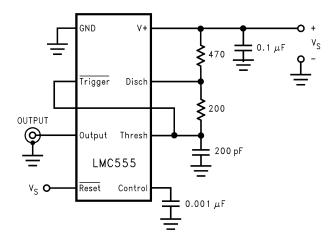
(1) All voltages are measured with respect to the ground pin, unless otherwise specified.

6 Parameter Measurement Information



For device pinout, see Section 4.

Figure 6-1. Test Circuit



For device pinout, see Section 4.

Figure 6-2. Maximum Frequency Test Circuit



7 Detailed Description

7.1 Overview

The LMC555 is a CMOS version of the industry standard 555 series general-purpose timers. In addition to the standard SOIC, VSSSOP, and PDIP packages, the LMC555 is also available in a chip-sized package (8-bump DSBGA) using TI's DSBGA package technology. The LMC555 offers the same capability of generating accurate time delays and frequencies as the LM555 but with much lower power dissipation and supply current spikes. When operated as a one-shot, the time delay is precisely controlled by a single external resistor and capacitor. In the astable mode, the oscillation frequency and duty cycle are accurately set by two external resistors and one capacitor. The use of TI's LMCMOS process extends both the frequency range and the low supply capability.

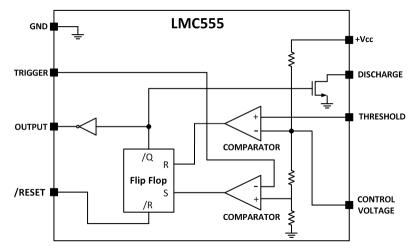
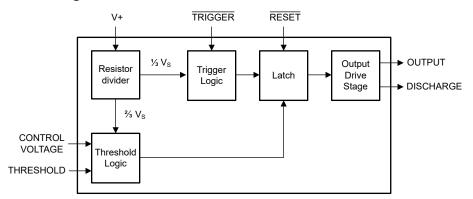


Figure 7-1. Simplified Schematic

7.2 Functional Block Diagram





7.3 Feature Description

7.3.1 Low-Power Dissipation

The LMC555 offers the same capability of generating accurate time delays and frequencies as the LM555 but with much lower power dissipation. A power dissipation of less than 0.2 mW can be achieved with a 1.5-V operating supply voltage and less than 1 mW with a 5-V operating supply voltage. The use of TI's LMCMOS process allows this low supply current and voltage capability. Reduced supply current spikes during output transitions and extremely low reset, trigger and threshold currents also provide low power dissipation advantages with the LMC555.

7.3.2 Various Packages and Compatibility

There are various packages available for use of the LMC555. In addition to the standard package (8-pin SOIC, VSSOP, and PDIP, the LMC555 is also available in a chip-sized package (8-bump DSBGA). The PDIP, SOIC, and VSSOP packages for the LMC555 are pin-for-pin compatible with the 555 series of timers (NE555/SE555/LM555) allowing flexibility in design and unnecessary modifications to PCB schematics and layouts.

7.3.3 Operates in Both Astable and Monostable Mode

The LMC555 can operate in both astable and monostable mode depending on the application requirements.

- Monostable mode: The LMC555 timer acts as a "one-shot" pulse generator. The pulse begins when the LMC555 timer receives a signal at the trigger input that falls below a 1/3 of the voltage supply. The width of the output pulse is determined by the time constant of an RC network. The output pulse ends when the voltage on the capacitor equals 2/3 of the supply voltage. The output pulse width can be extended or shortened depending on the application by adjusting the R and C values.
- Astable (free-running) mode: The LMC555 timer can operate as an oscillator and puts out a continuous stream of rectangular pulses having a specified frequency. The frequency of the pulse stream depends on the values of RA, RB, and C.



7.4 Device Functional Modes

7.4.1 Monostable Operation

In this mode of operation, the timer functions as a one-shot (Figure 7-2). The external capacitor is initially held discharged by internal circuitry. Upon application of a negative trigger pulse of less than $1/3 V_S$ to the TRIGGER pin, the flip-flop is set, which both releases the short circuit across the capacitor and drives the output high.

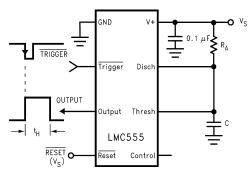


Figure 7-2. Monostable (One-Shot)

The voltage across the capacitor then increases exponentially for a period of $t_H = 1.1 R_A C$. This period is also the time that the output stays high, at the end of which time the voltage equals 2/3 V_S. The comparator then resets the flip-flop, which in turn discharges the capacitor and drives the output to the low state. Figure 7-3 shows the waveforms generated in this mode of operation. Because the charge and the threshold level of the comparator are both directly proportional to supply voltage, the timing internal is independent of supply.

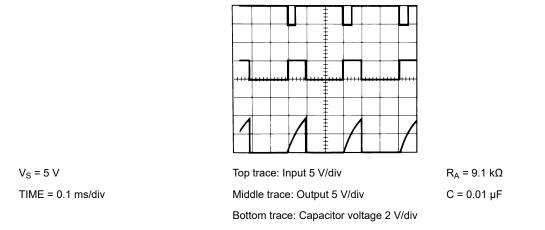


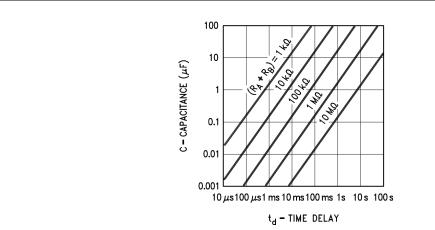
Figure 7-3. Monostable Waveforms

RESET overrides TRIGGER, which can override THRESHOLD. Therefore, ensure that the trigger pulse is shorter than the desired t_{H} . The minimum pulse duration for TRIGGER is 20 ns, and is 400 ns for RESET. During the timing cycle when the output is high, the further application of a trigger pulse does not effect the circuit as long as the trigger input is returned high at least 10 µs before the end of the timing interval. However the circuit can be reset during this time by the application of a negative pulse to the RESET pin. The output remains in the low state until a trigger pulse is applied again.



When the reset function is not used, connect the RESET pin to V+ to avoid any possibility of false triggering. Figure 7-4 is a nomograph for easy determination of RC values for various time delays.

Note



In monostable operation, drive the trigger high before the end of timing cycle.

Figure 7-4. Time Delay

7.4.2 Astable Operation

If the circuit is connected as shown in Figure 7-5 (TRIGGER and THRESHOLD pins connected together), the circuit triggers and free runs as a multivibrator. The external capacitor charges through $R_A + R_B$ and discharges through R_B . Thus, the duty cycle can be precisely set by the ratio of these two resistors.

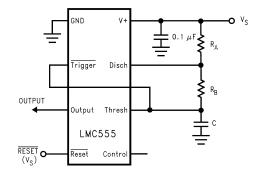


Figure 7-5. Astable (Variable Duty Cycle Oscillator)

In this mode of operation, the capacitor charges and discharges between $1/3 V_S$ and $2/3 V_S$. As in the triggered mode, the charge and discharge times, and therefore, the frequency are independent of the supply voltage.

Figure 7-6 shows the waveform generated in this mode of operation.



V_S = 5 V TIME = 20

	Top trace: Output 5 V/div	R _A = 1.78 kΩ
μs/div	Bottom trace: Capacitor voltage 1 V/div	R _B = 4.12 kΩ
		C = 0.01 µF

Figure 7-6. Astable Waveforms

The charge time (output high) is given by

$t_1 = 0.693 (R_A + R_B)C$	(1)
And the discharge time (output low) by:	
t ₂ = 0.693 (R _B)C	(2)
Thus the total period is:	

$$T = t_1 + t_2 = 0.693 (R_A + 2R_B)C$$
(3)

The frequency of oscillation is:

$$f = \frac{1}{T} = \frac{1.44}{(R_A + 2R_B)C}$$
(4)

Figure 7-7 can be used for quick determination of these RC Values. The duty cycle, as a fraction of total period that the output is low, is:

$$D = \frac{R_B}{R_A + 2R_B}$$
(5)

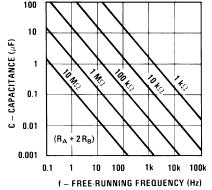


Figure 7-7. Free-Running Frequency



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

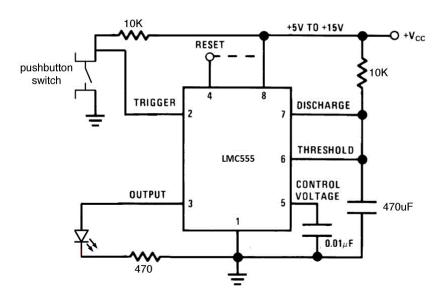
8.1 Application Information

The LMC555 timer can be used a various configurations, but the most commonly used configuration is in monostable mode. A typical application for the LMC555 timer in monostable mode is to turn on an LED for a specific time duration. A pushbutton is used as the trigger to output a high pulse when trigger pin is pulsed low. This simple application can be modified to fit any application requirement.

8.2 Typical Applications

8.2.1 Flash LED in Monostable Mode

Figure 8-1 shows the schematic of an LMC555 that flashes an LED in monostable mode.





8.2.1.1 Design Requirements

The main design requirement for this application requires calculating the duration of time that the output stays high. The duration of time depends on the R and C values (shown in Figure 7-4) and is calculated by the following equation:

 $t = 1.1 \times R \times C$ seconds

(6)



8.2.1.2 Detailed Design Procedure

To allow the LED to flash on for a noticeable amount of time, a 5-second time delay was chosen for this application. Using Equation 6, R × C equals 4.545.

If R is chosen as 100 k Ω , C = 45.4 μ F. The values of R = 100 k Ω and C = 47 μ F were chosen based on standard values of resistors and capacitors.

A momentary push button switch connected to ground is connected to the trigger input with a $10-k\Omega$ current limiting resistor pull up to the supply voltage. When the push button is pressed, the TRIGGER pin goes to GND. An LED is connected to the OUTPUT pin with a current limiting resistor in series from the output of the LMC555 to GND. The RESET pin is not used and was connected to the supply voltage.

8.2.1.3 Application Curve

The data shown in Figure 8-2 were collected with the circuit used in the typical applications section. The LMC555 was configured in the monostable mode with a time delay of 5.17 s. The waveforms correspond to:

- Top Waveform (Blue) Capacitor voltage
- Middle Waveform (Purple) TRIGGER
- Bottom Waveform (Green) OUTPUT

As the TRIGGER pin pulses low, the capacitor voltage starts charging and the output goes high. The output goes low as soon as the capacitor voltage reaches 2/3 of the supply voltage, which is the time delay set by the R and C value. For this example, the time delay is 5.17 seconds.

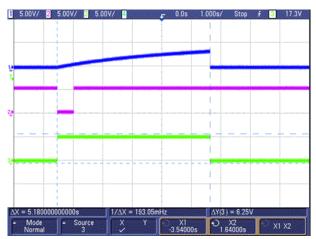


Figure 8-2. TRIGGER, Capacitor Voltage, and OUTPUT Waveforms in Monostable Mode



8.2.2 Frequency Divider

The monostable circuit of Figure 8-3 can be used as a frequency divider by adjusting the length of the timing cycle. Figure 8-4 shows the waveforms generated in a divide by three circuit.

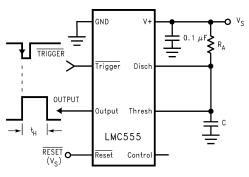


Figure 8-3. Monostable (One-Shot)

8.2.2.1 Design Requirements

Design a frequency divider by adjusting the length of the timing cycle.

8.2.2.2 Application Curve

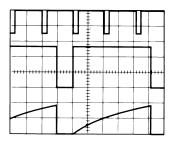


Figure 8-4. Frequency Divider Waveforms

8.2.3 Pulse Width Modulator

When the timer is connected in the monostable mode and triggered with a continuous pulse train, the output pulse width can be modulated by a signal applied to the control voltage terminal. Figure 8-5 shows the circuit, and in Figure 8-6 are some waveform examples.

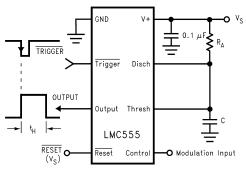


Figure 8-5. Pulse Width Modulator

8.2.3.1 Design Requirements

Modulator the output pulse width by the signal applied to the control voltage terminal.



8.2.3.2 Application Curve

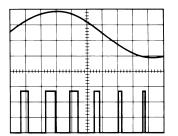


Figure 8-6. Pulse Width Modulator Waveforms

8.2.4 Pulse Position Modulator

This application uses the timer connected for astable operation, as in Figure 8-7, with a modulating signal again applied to the control voltage terminal. The pulse position varies with the modulating signal, since the threshold voltage and hence the time delay is varied. Figure 8-8 shows the waveforms generated for a triangle wave modulation signal.

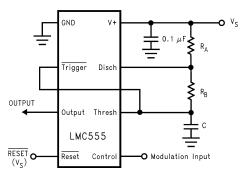


Figure 8-7. Pulse Position Modulator

8.2.4.1 Design Requirements

Using astable operation vary the pulse position with a modulating signal applied to the control voltage terminal.

8.2.4.2 Application Curve

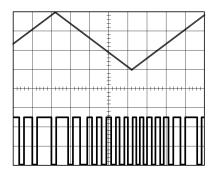


Figure 8-8. Pulse Position Modulator Waveforms



(7)

8.2.5 50% Duty Cycle Oscillator

The frequency of oscillation is:

$$f = 1/(1.4 R_C C)$$

GND ٧ **o** v_s 느 0.1 μF Т Trigger Disch ALTERNATE OUTPUT OUTPUT Output Thresh LMC555 $\overline{\mathbf{P}}_{(V_S)}^{\mathsf{RESET}}\mathbf{O}$ eset Contro R_{C}

Figure 8-9. 50% Duty Cycle Oscillator

8.2.5.1 Design Requirements

An oscillator with a 50% duty cycle output.





8.3 Power Supply Recommendations

The LMC555 requires a voltage supply within 1.5 V to 15 V. Adequate power supply bypassing is necessary to protect associated circuitry; the minimum recommended is 0.1 μ F in parallel with 1- μ F electrolytic. Place the bypass capacitors as close as possible to the LMC555 and minimize the trace length.

8.4 Layout

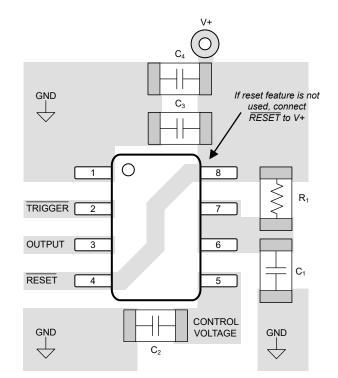
8.4.1 Layout Guidelines

Standard PCB rules apply to routing the LMC555. Keep the 0.1 μ F capacitor in parallel with a 1- μ F electrolytic capacitor as close as possible to the LMC555. Place the capacitor used for the time delay as close as possible to the DISCHARGE pin. Use a ground plane on the bottom layer to provide better noise immunity and signal integrity.

8.4.2 Layout Example

The figure below is the basic layout for various applications.

- C1 based on time delay calculations
- C2 0.01 µF bypass capacitor for control voltage pin
- C3 0.1 µF bypass ceramic capacitor
- C4 1-µF electrolytic bypass capacitor
- R1 based on time delay calculations
- U1 LMC555







9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision M (July 2016) to Revision N (March 2024)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Updated wording of Features bullets for clarity	
•	Updated GROUND and V+ pin types in Pin Configuration and Functions	
•	Changed V _{CC} to V+ in <i>Pin Configuration and Functions</i>	
•	Added (V+) to DISCHARGE description in Pin Configuration and Functions	
•	Updated R _{0JA} and added detailed thermal characteristics for all packages in Thermal Information	4
•	Moved timing accuracy, timing shift with supply, timing shift with temperature, astable frequency, maxim	
	frequency, output rise and fall times, and trigger propagation delay parameters from <i>Electrical Characte</i>	ristics
	to Switching Characteristics	5
•	Changed supply current (I _S) typical values from 50 μ A to 130 μ A at V _S = 1.5 V; from 100 μ A to 180 μ A at V _S = 1.5 V;	•
	1.5 V; and from 150 μ A to 220 μ A at V _S = 12 V, in <i>Electrical Characteristics</i>	<mark>5</mark>
•	Changed supply current (I _S) max value from 150 µA to 200 µA at V _S = 1.5 V in <i>Electrical Characteristic</i>	s <mark>5</mark>
•	Changed reset current (I _{RES}) test condition to V _{RES} = V _S in <i>Electrical Characteristics</i>	5
•	Added new reset current (IRES) typical value for test condition VRES = 0 V to Electrical Characteristics	<mark>5</mark>
•	Updated Switching Characteristics to clarify that values are specified by design, characterization, or bot	նի <mark>5</mark>
•	Changed units of timing shift with temperature from %V to %/V (typo) in Switching Characteristics	5
•	Changed functional block diagram to simplified schematic and moved to Overview	7
•	Updated Functional Block Diagram	7
•	Changed values of R_A from 3.9 k Ω to 1.78 k Ω , and R_B and 9 k Ω to 4.12 k Ω in Figure 7-6	10
•	Changed "LM555" to "LMC555" (typo) in Typical Applications	12
•	Updated figure in Layout Example	17



C	hanges from Revision L (February 2016) to Revision M (July 2016)	Page
•	Changed order of <i>Features</i>	
	Changed stable to astable (typo)	
	Changed stable to astable - typo.	
	Changed beings to begins typo	
•	Changed typo LM555 to LMC555.	12
	Changed typo LM555 to LMC555.	
	Added additional applications.	

С	hanges from Revision K (January 2015) to Revision L (February 2016)	Page
•	Changed typo - temp range from 185 to 85	4

UI	nanges from Revision J (March 2013) to Revision K (October 2014)	Page
	Added Pin Configuration and Functions, ESD Ratings, Feature Description, Device Functional Modes,	
	Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation	
	Support, and Mechanical, Packaging, and Orderable Information sections	
	nanges from Revision I (March 2013) to Revision J (March 2013)	Pag

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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